NSN 5961-00-163-5803

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View Online at https://aerobasegroup.com/nsn/5961-00-163-5803 **Inclosure Material:** Metal **Overall Length:** 0.567 inches **Overall Height:** 0.500 inches **Overall Width:** Between 0.710 inches and 0.730 inches **Function For Which Designed:** Amplifier and microwave and oscillator **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to base voltage/static/emitter open and 55.0 collector to emitter reverse voltage and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 29.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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